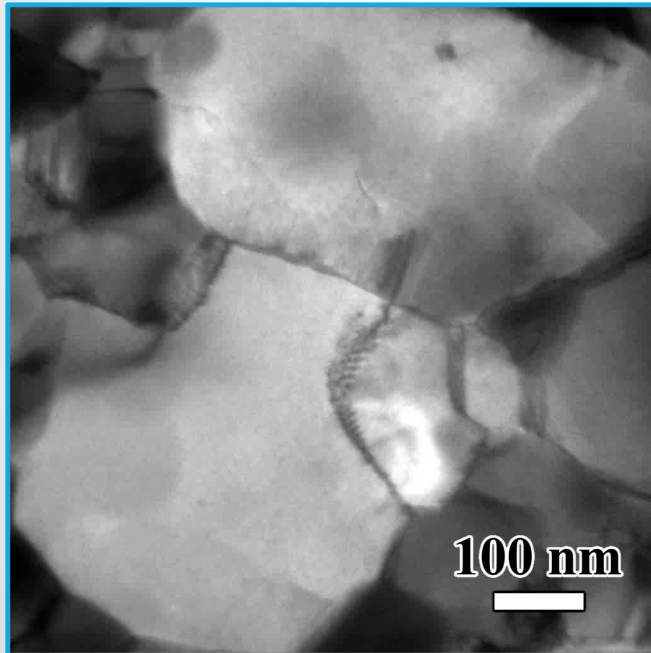




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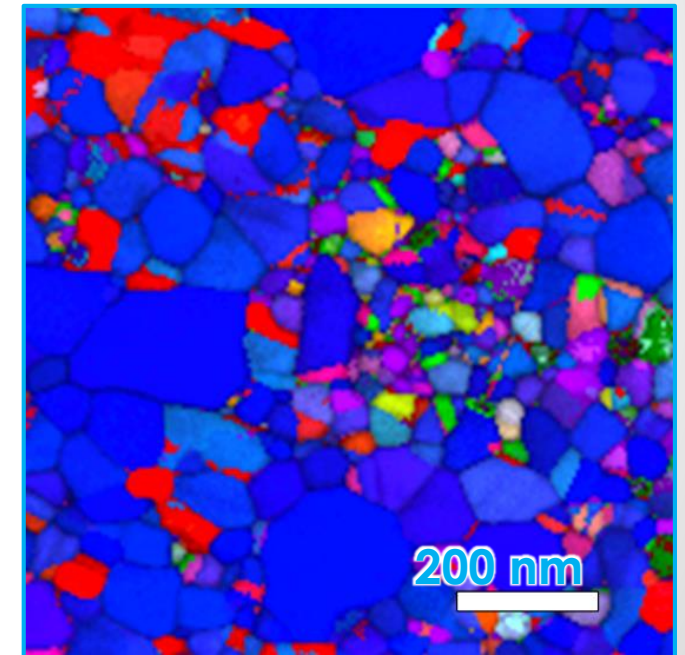
SAND2016-10013C

# Directly Observing Structural Evolution during Sequential and Concurrent Helium Implantation and Heavy Ion Irradiation



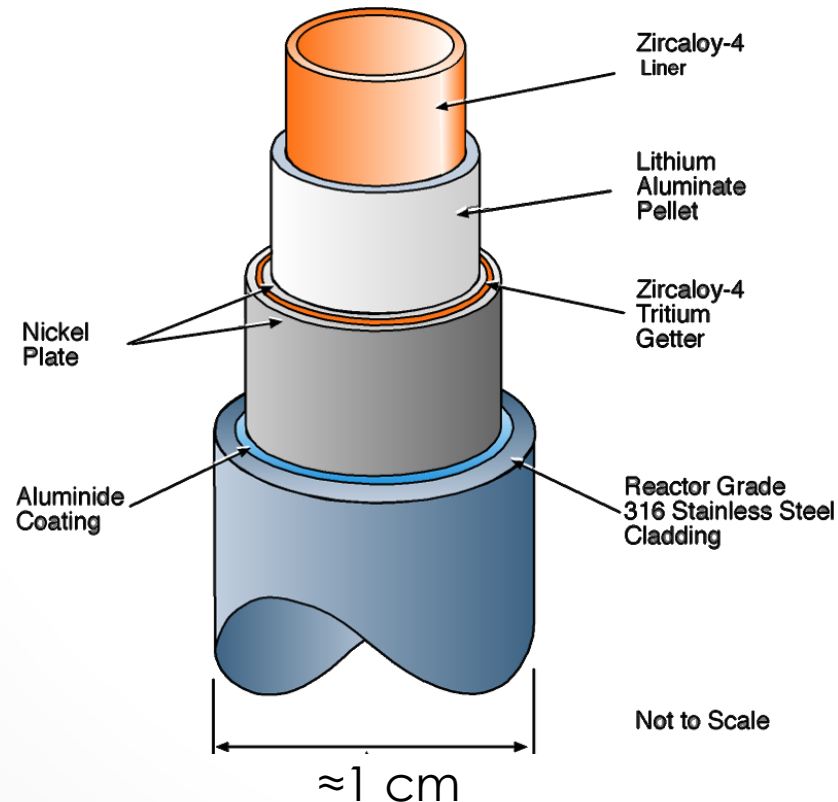
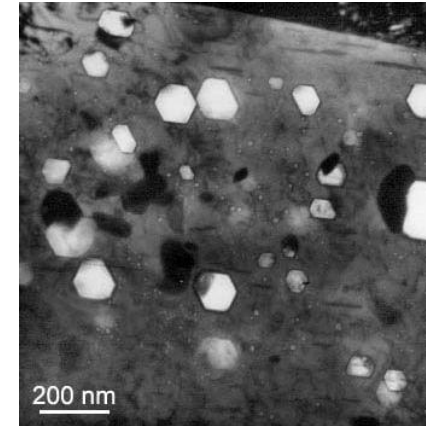
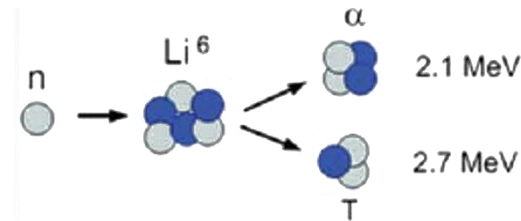
Daniel Bufford, Claire Chisholm,  
Brittany Muntifering, and Khalid Hattar

Sandia National Laboratories  
Albuquerque, NM, USA



# Nuclear Reactors and TPBARs

Tritium Producing Burnable Absorber Rod: device that uses neutron flux from a nuclear reactor to produce tritium.

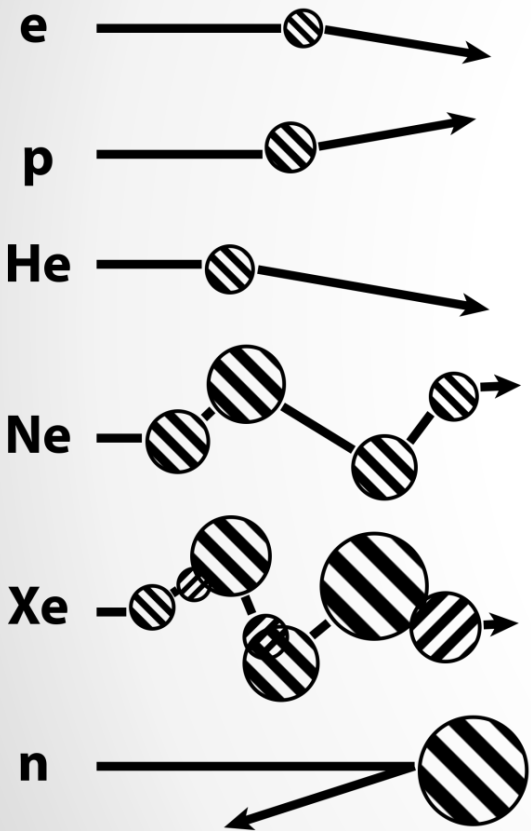


## Tough environment for materials!

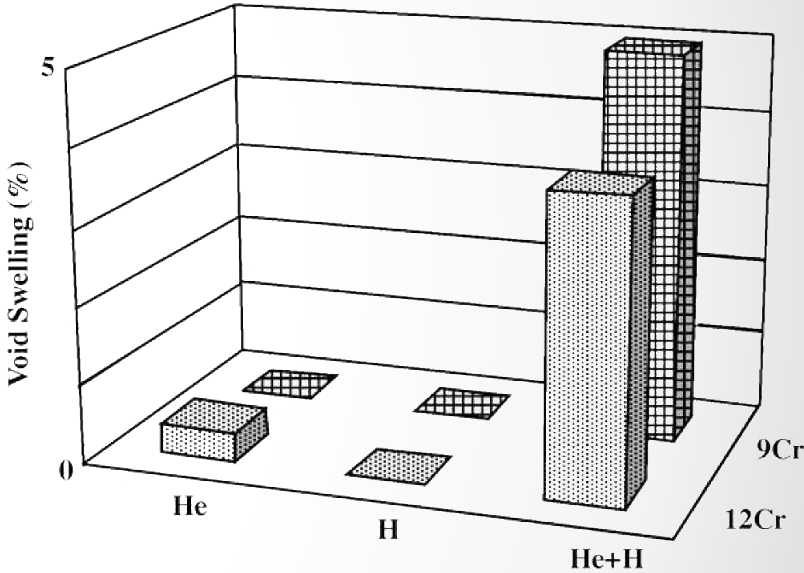
- Displacement Damage
- Helium Implantation
- Tritium Implantation
- Elevated Temperatures
- Corrosion

Need to understand the individual factors, and their interactions.

# Ion beams can simulate radiation conditions to accelerate materials research and development



	Neutrons	Ions
Radiation Conditions	Real	Simulated
Experiment times	Months to years	Hours to days
Residual radioactivity?	Yes: necessitates special material handling.	Typically none, or short term activation
Depths reached	Often orders of magnitude deeper than ions	Up to tens of $\mu\text{m}$



T. Tanaka, et al., J Nucl Mater 2004.

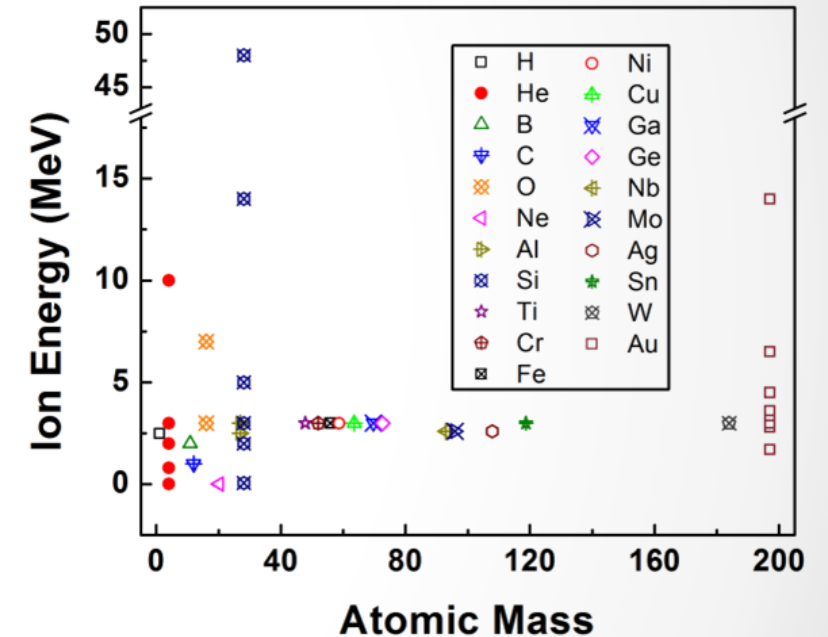
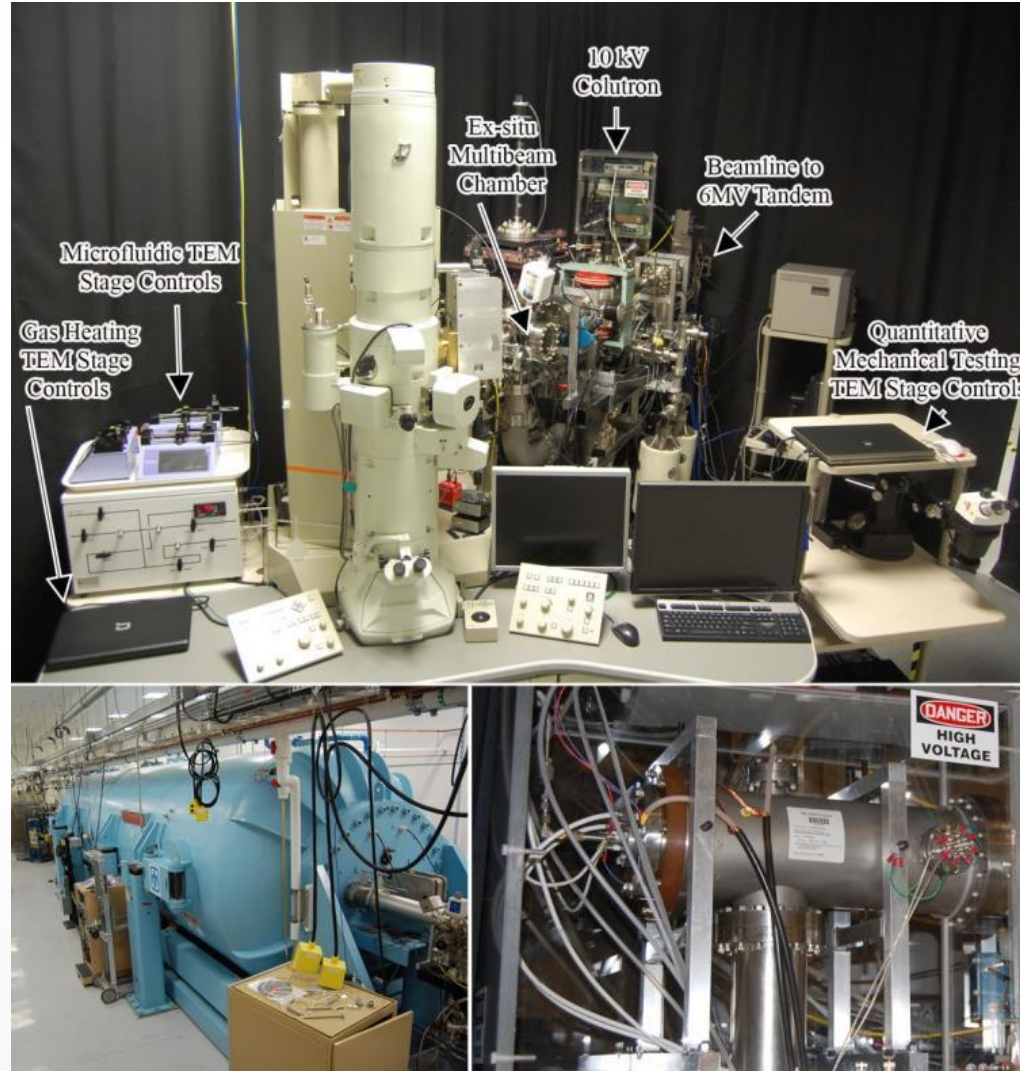
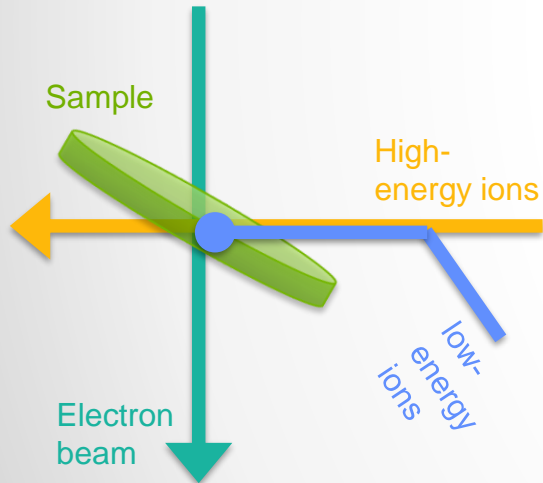
Multiple beam concurrent irradiation produces effects not seen with sequential irradiation, however the difficulty of performing triple-beam irradiation has resulted in a limited number of facilities world wide.



# Sandia's Concurrent *In situ* Ion Irradiation TEM (I<sup>3</sup>TEM) Facility

Collaborators: D.L. Buller, K. Hattar, and J. Scott

- 10 kV Colutron
- 200 kV TEM
- 6 MV Tandem

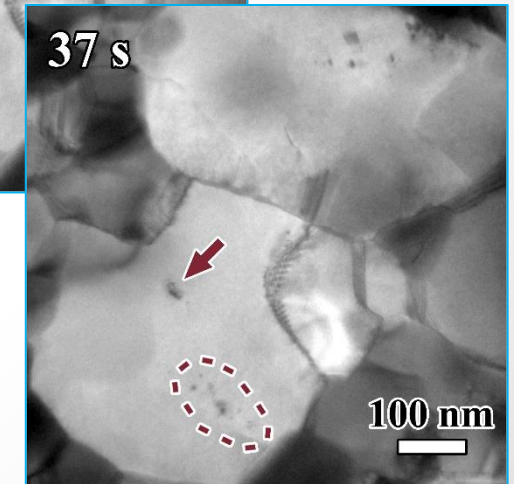
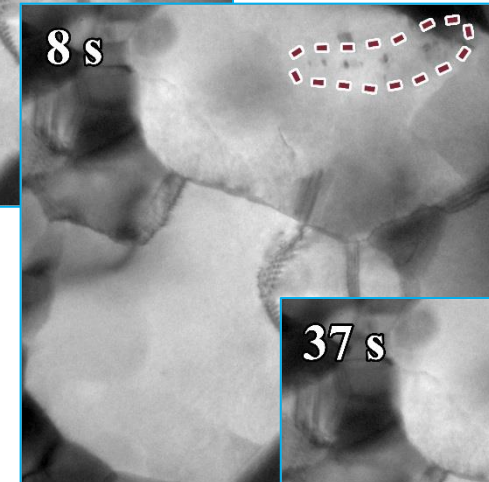
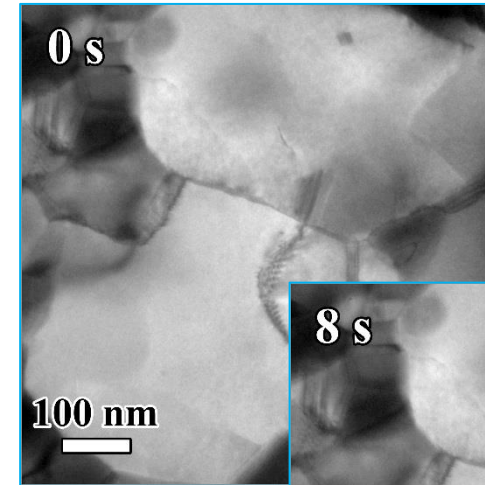
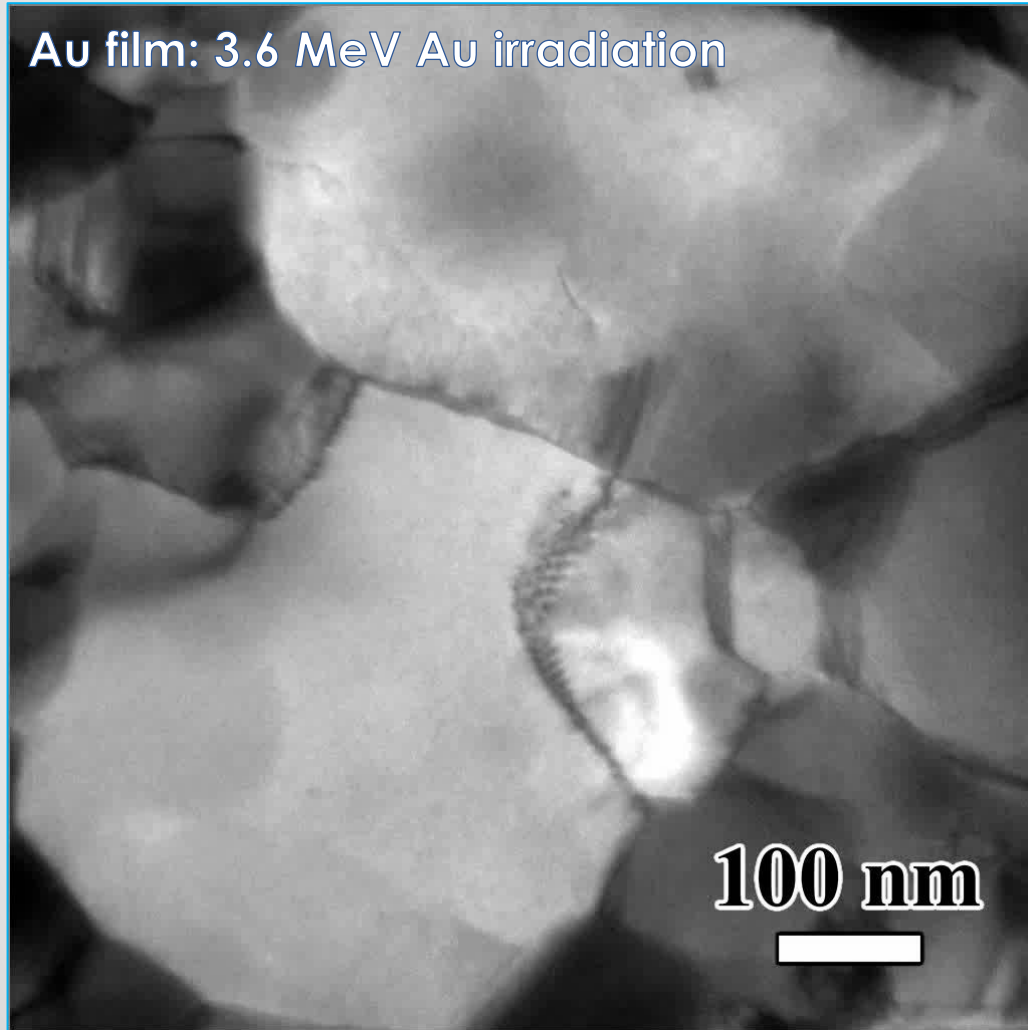


Direct real time observation of ion irradiation, ion implantation, or both with nanometer resolution

# Displacement Damage *In Situ*

Video playback speed x5.

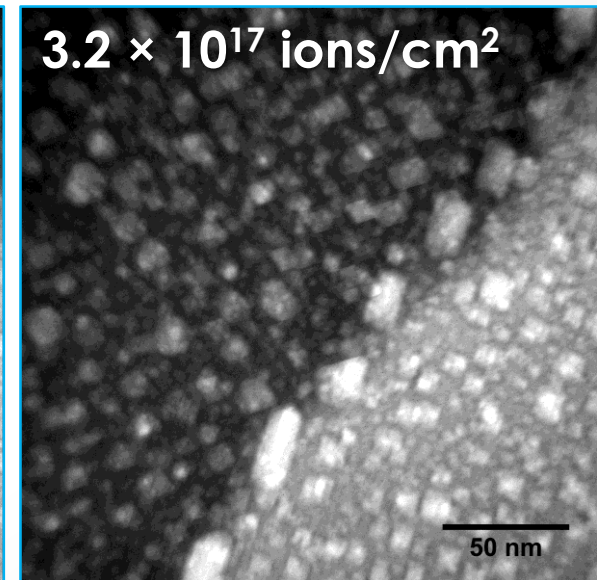
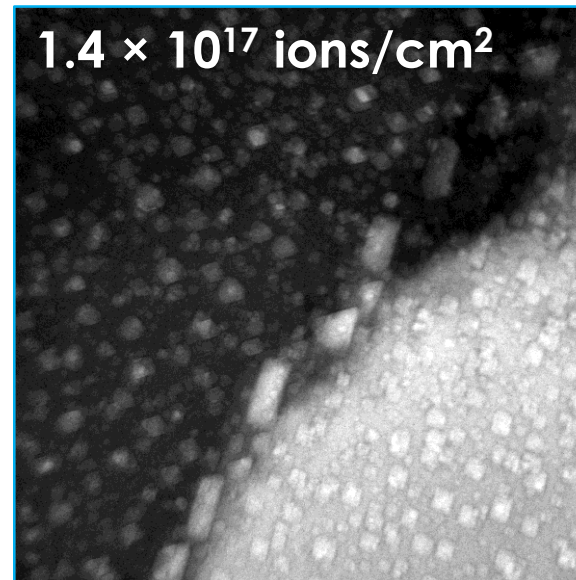
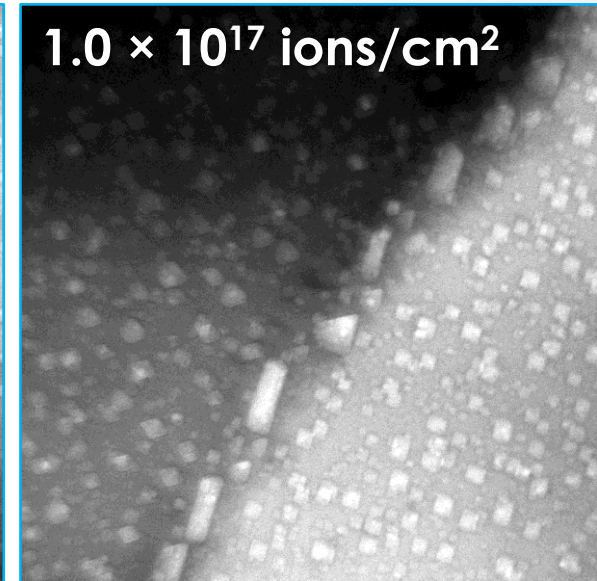
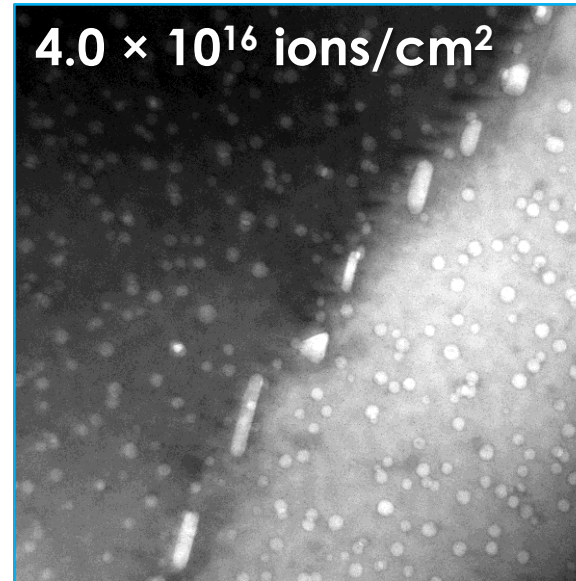
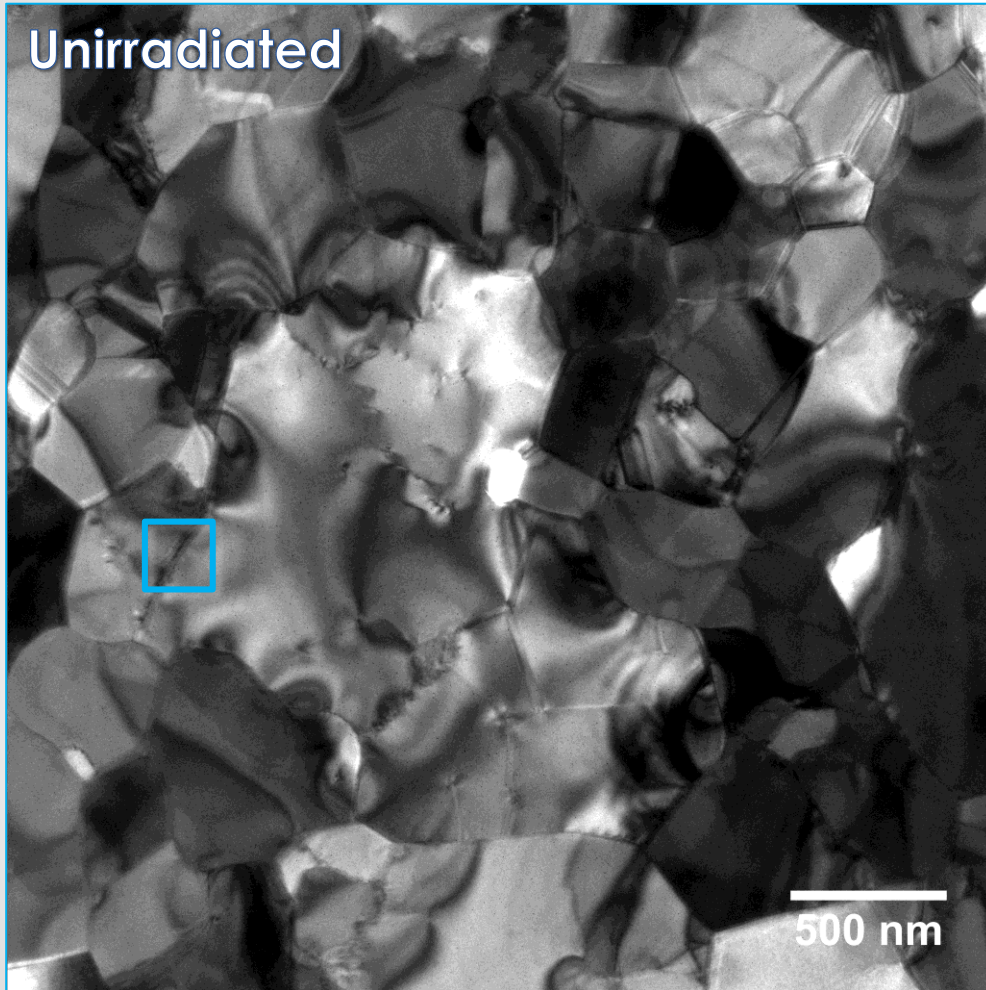
Au film: 3.6 MeV Au irradiation





# Helium Implantation *In situ*

Collaborators: C. Chisholm and A. Minor

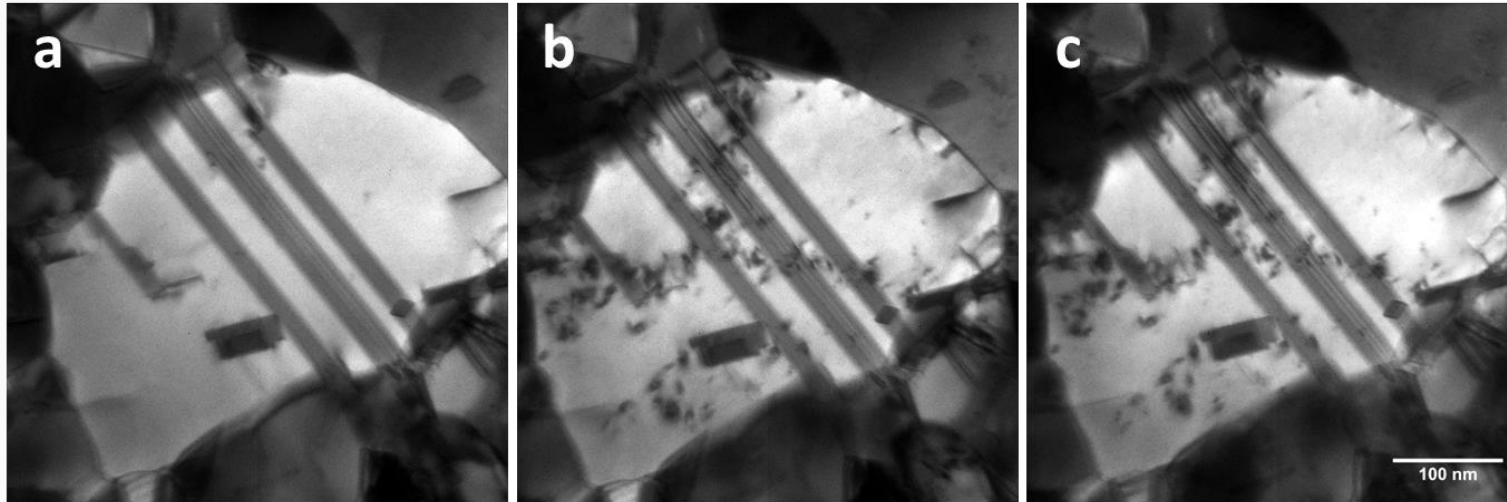


What happens when the radiation conditions are combined?

# Sequential Implantation & Irradiation

Collaborators: C. Chisholm and A. Minor

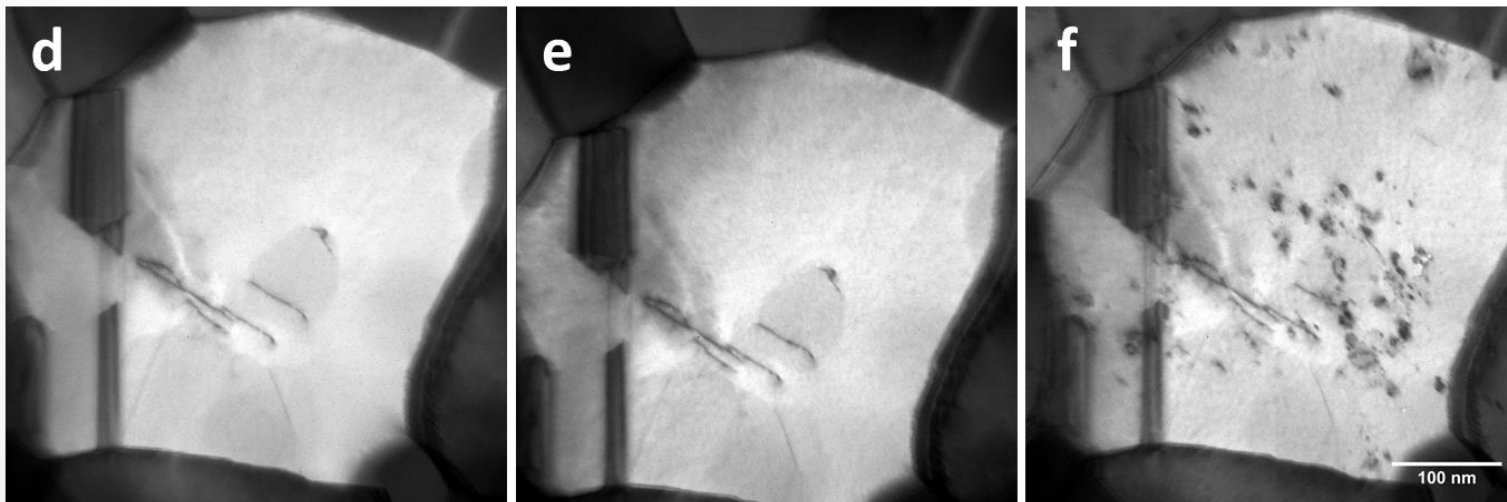
Successive Au<sup>4+</sup> then He<sup>4+</sup>



2.8 MeV Au then  
10 keV He

- Equal fluences:
  - Au  $3 \times 10^{10}$  ions/cm<sup>2</sup>
  - He  $2 \times 10^{15}$  ions/cm<sup>2</sup>

Successive He<sup>4+</sup> then Au<sup>4+</sup>



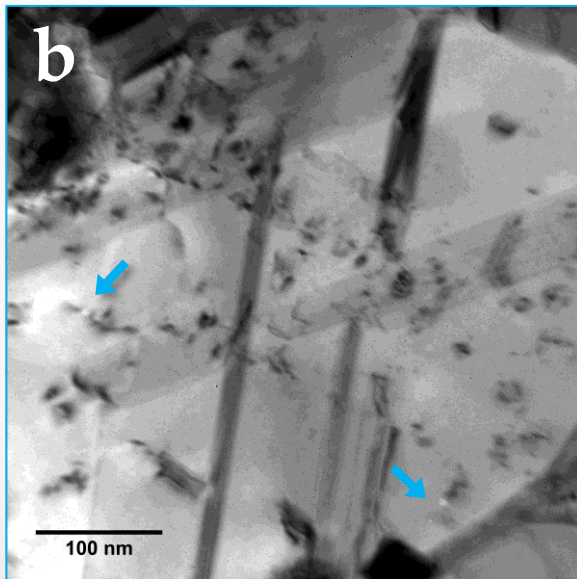
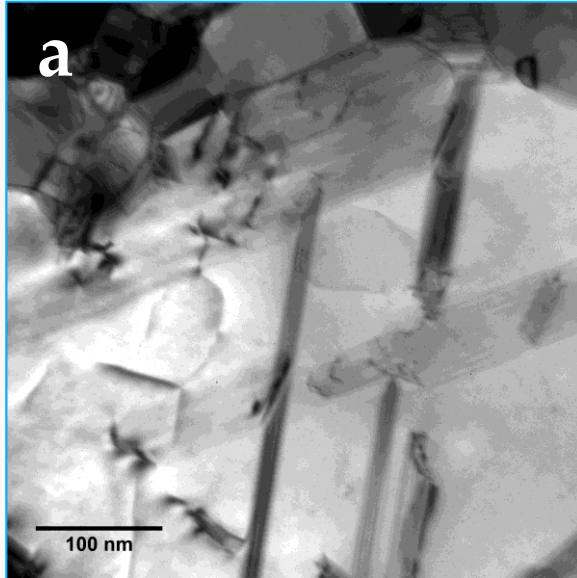
10 keV He  
then 2.8 MeV Au

**No noticeable  
differences between  
these sequential  
irradiation conditions.**

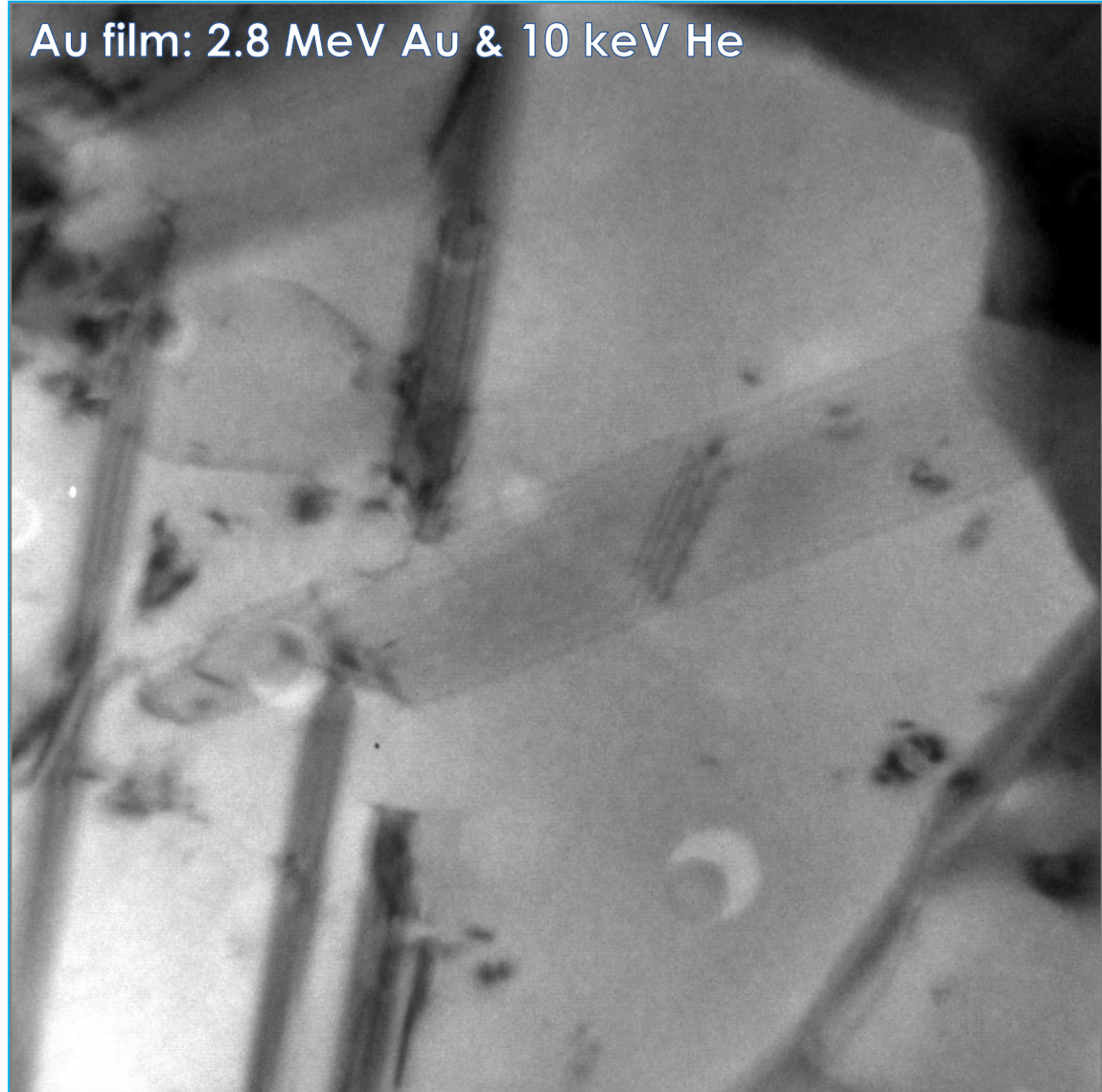


# Concurrent Implantation & Irradiation *In Situ*

Collaborators: C. Chisholm and A. Minor



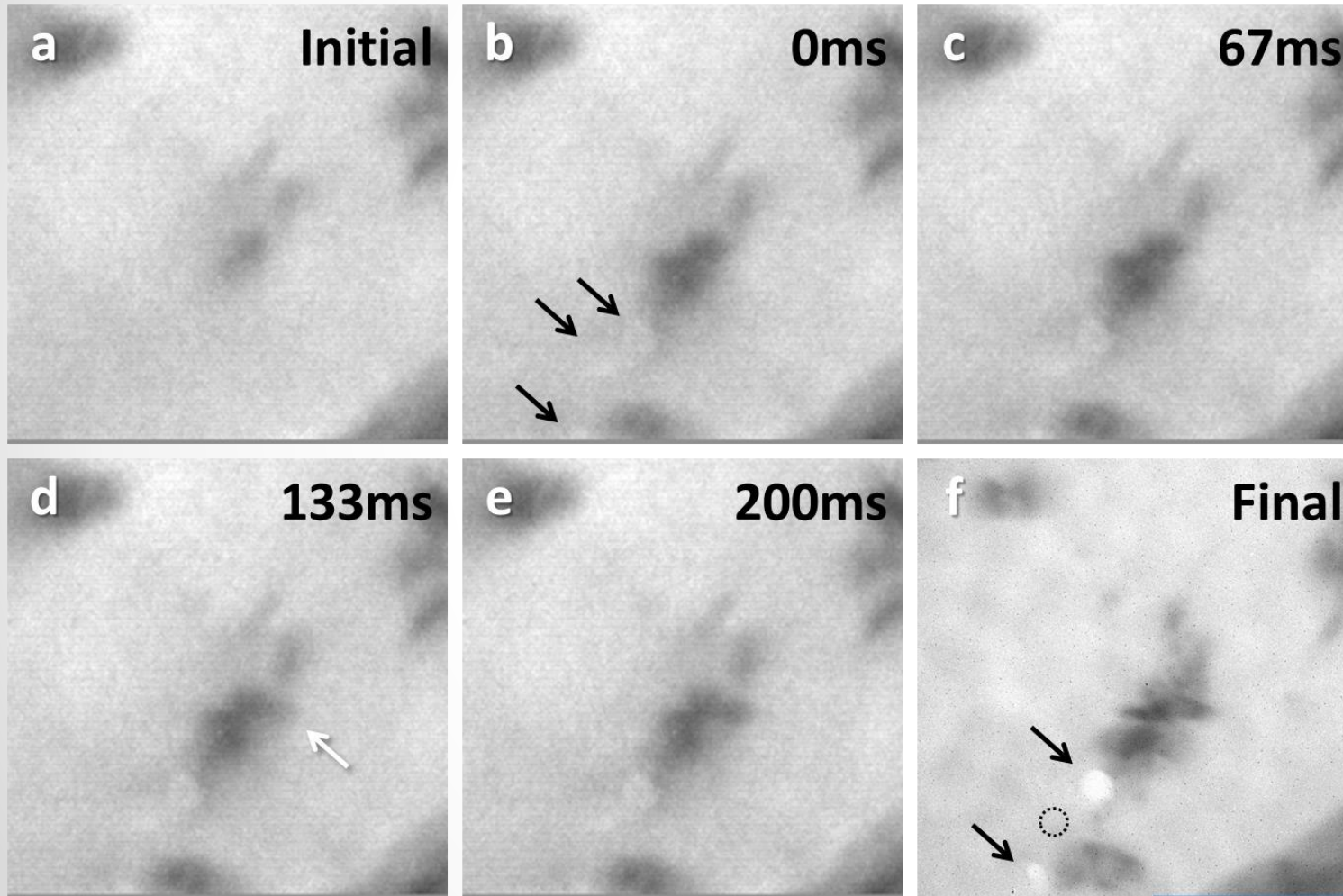
Au film: 2.8 MeV Au & 10 keV He





# Single Ion Strikes during Concurrent Irradiation: Direct Cavity Nucleation

Collaborators: C. Chisholm and A. Minor

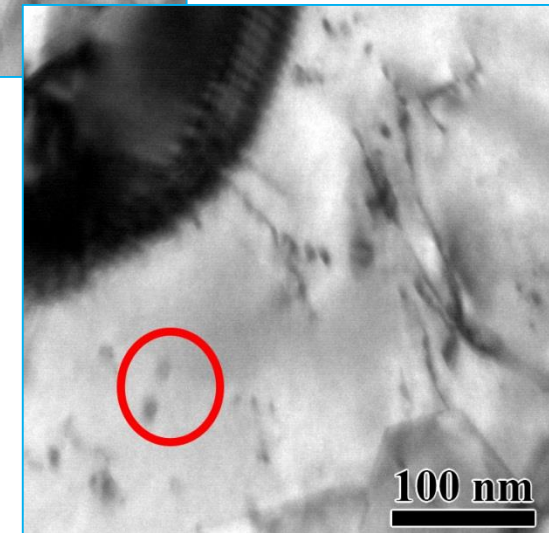
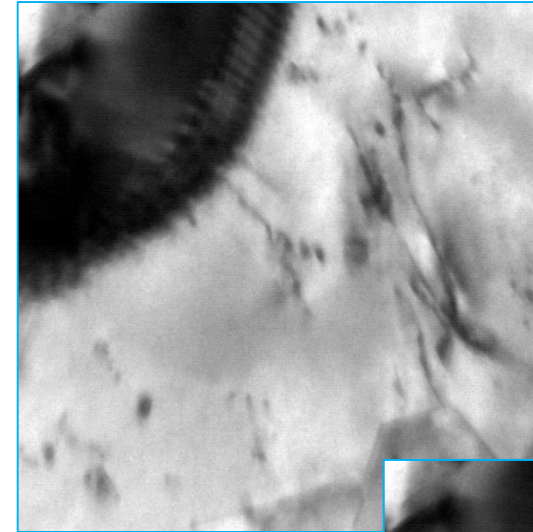
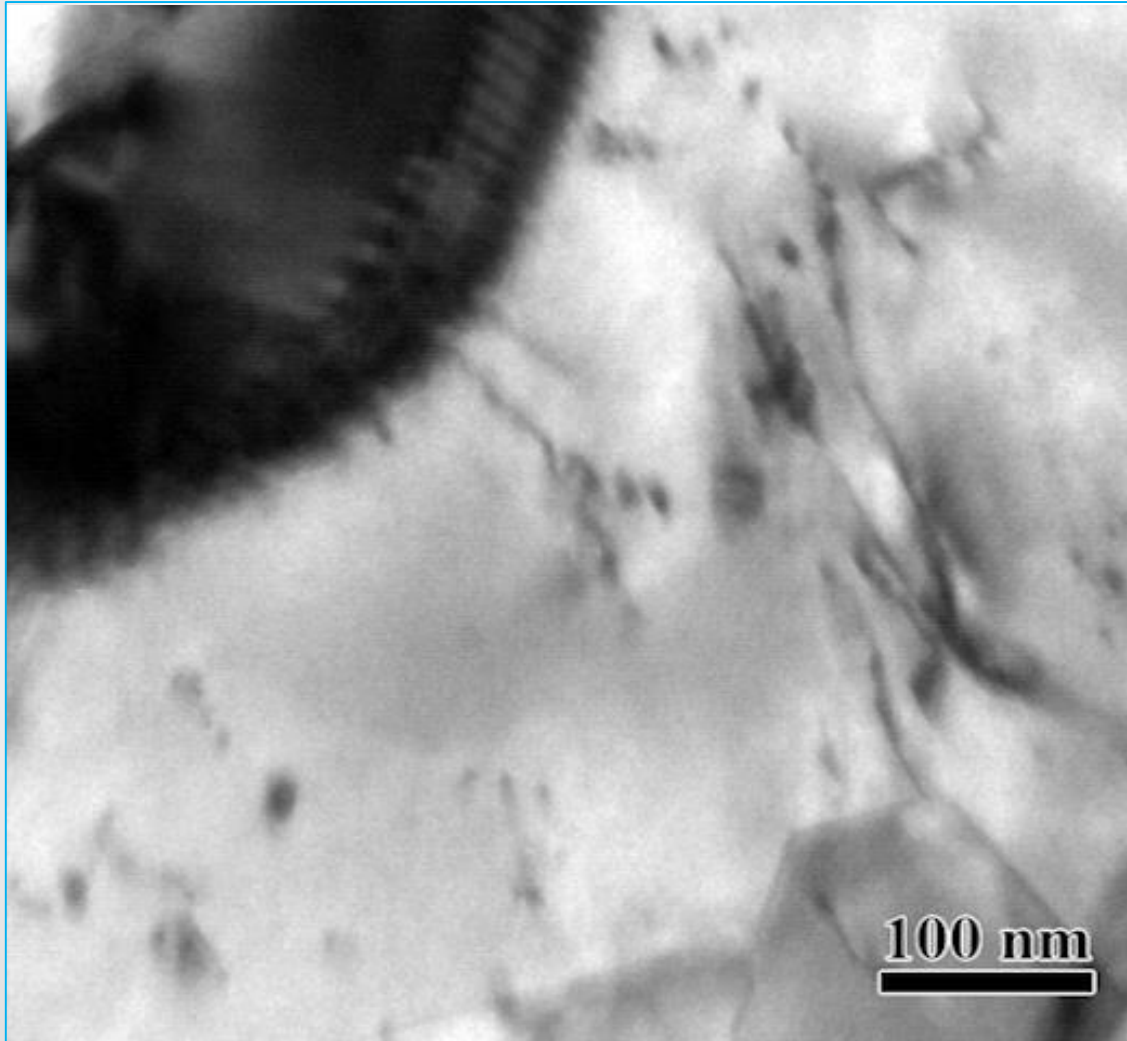


- a) Initial microstructure
- b) Cascade: Creation of dislocation loops, vacancy clusters, and three cavities
- d) Cascade damage still evolving
- e) Apparent stability
- f) Final microstructure: Only two remaining cavities

**Direct cavity nucleation process seen with concurrent irradiation that was not seen with sequential beams!**

# Triple beam irradiation: Au and $\text{He}^+/\text{D}_2^+$

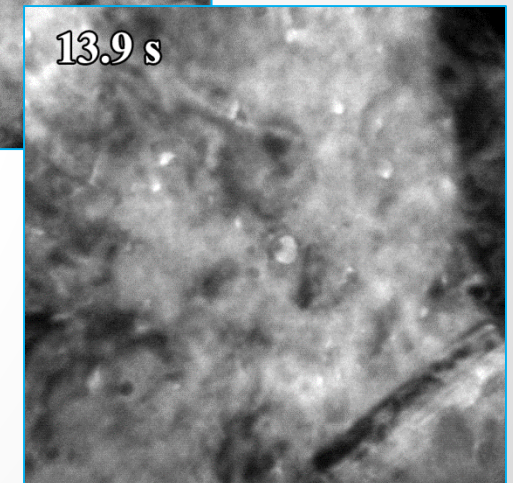
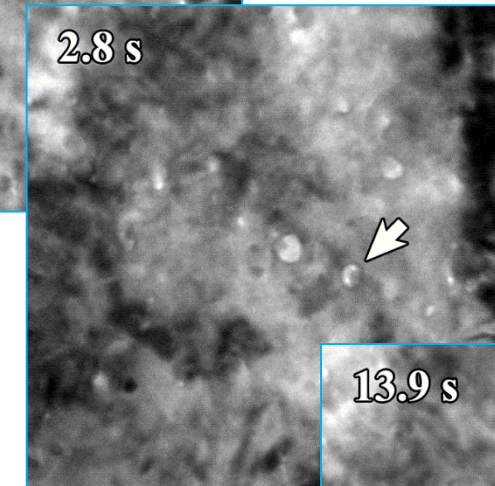
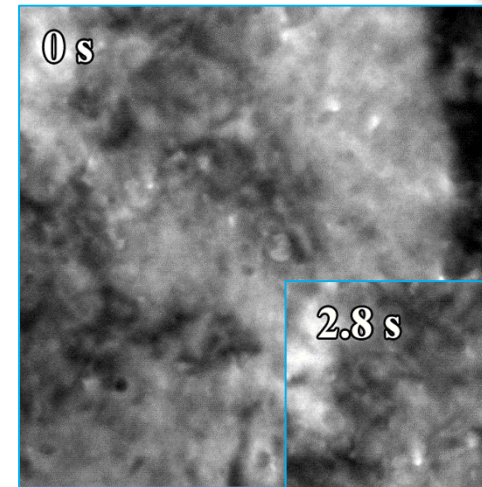
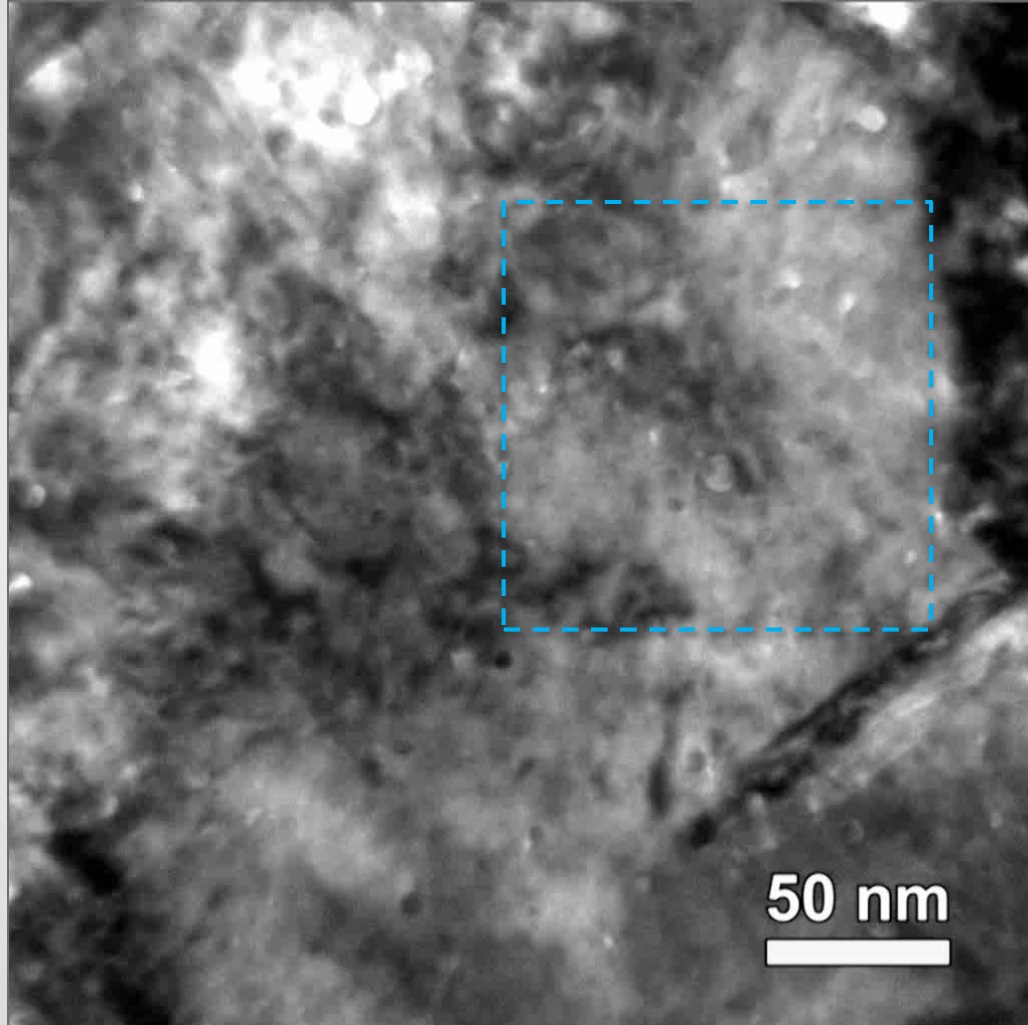
Video playback speed in real time.





# Triple beam irradiation: Au and $\text{He}^+/\text{D}_2^+$

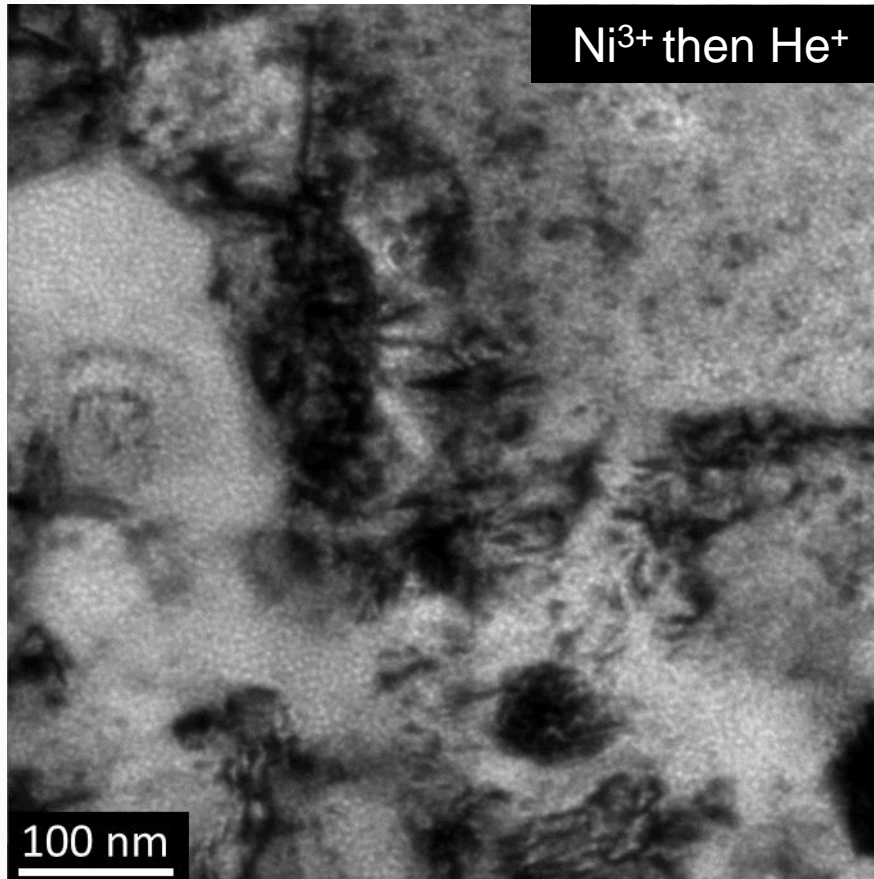
Video playback speed x1.5.



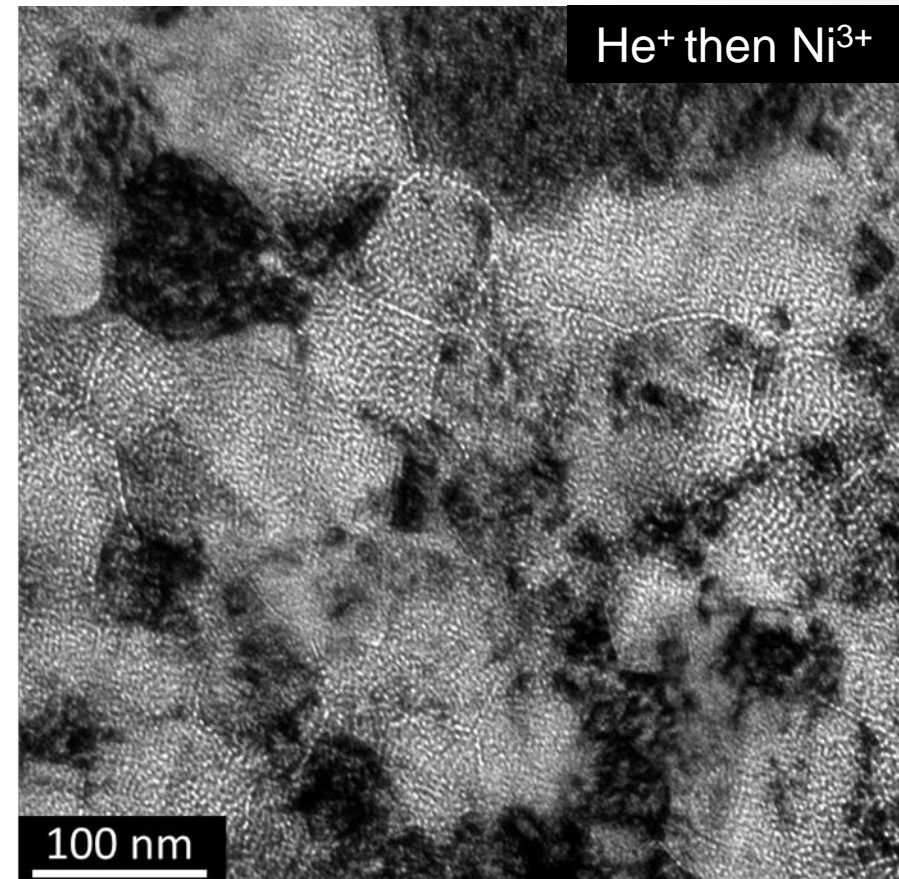
- Approximate fluence:
  - Au  $1.2 \times 10^{13}$  ions/cm<sup>2</sup>
  - He  $1.3 \times 10^{15}$  ions/cm<sup>2</sup>
  - D  $2.2 \times 10^{15}$  ions/cm<sup>2</sup>
- Cavity nucleation and disappearance

# Irradiation / Implantation Sequence Effect on Cavity Structure

- 10 keV He
- 3 MeV Ni



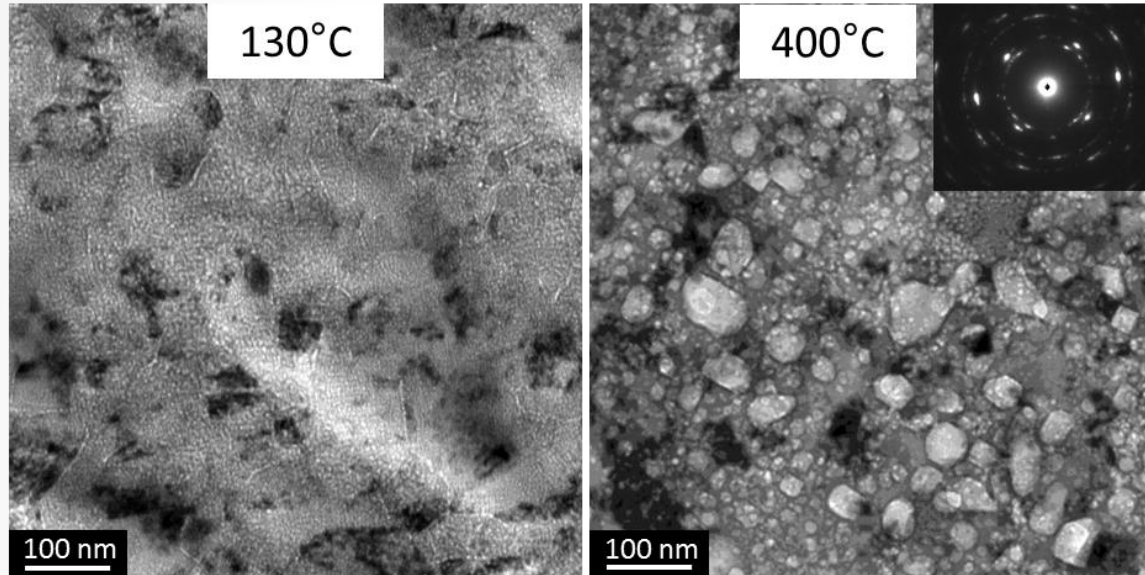
Evenly distributed cavities  
over the entire grain structure



Apparent higher  
concentration of cavities  
along grain boundaries

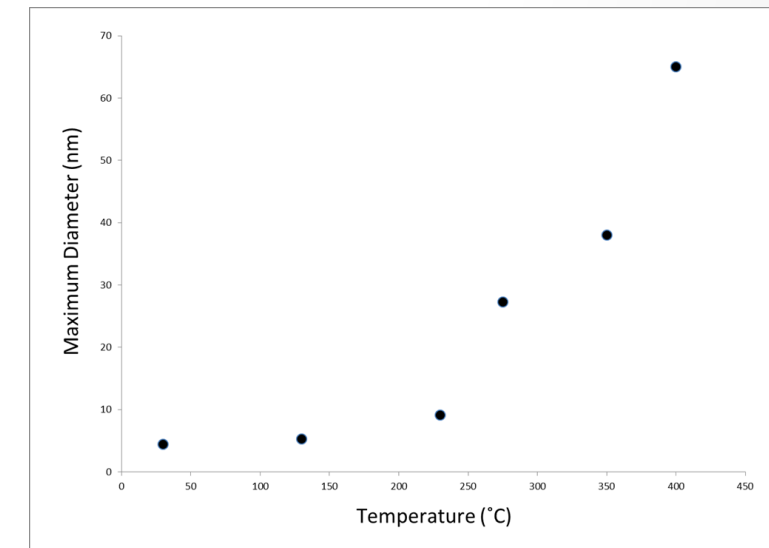
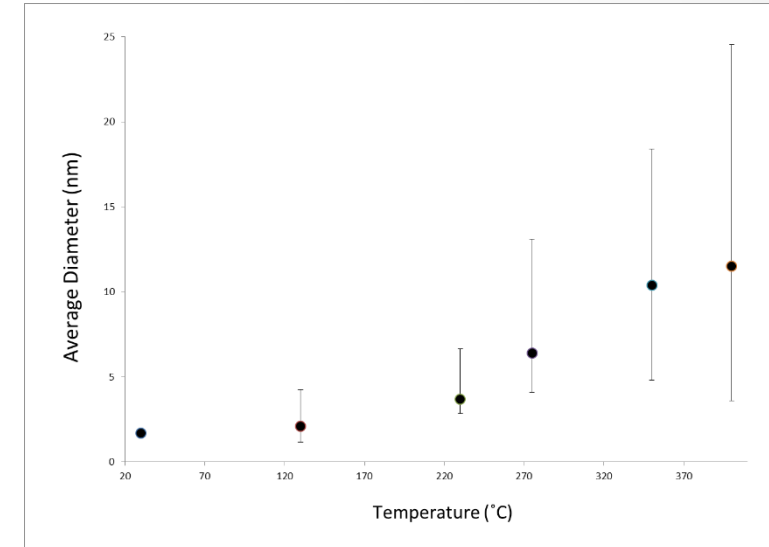
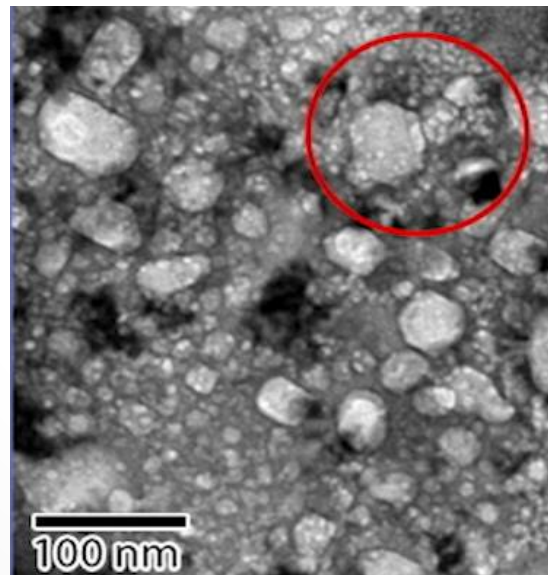


# *In Situ* Annealing of Sequentially Irradiated Ni: Cavity Growth



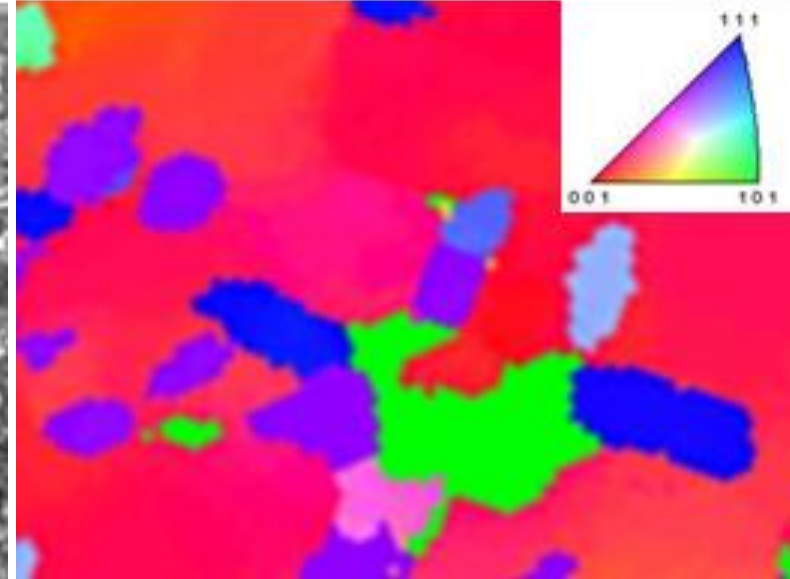
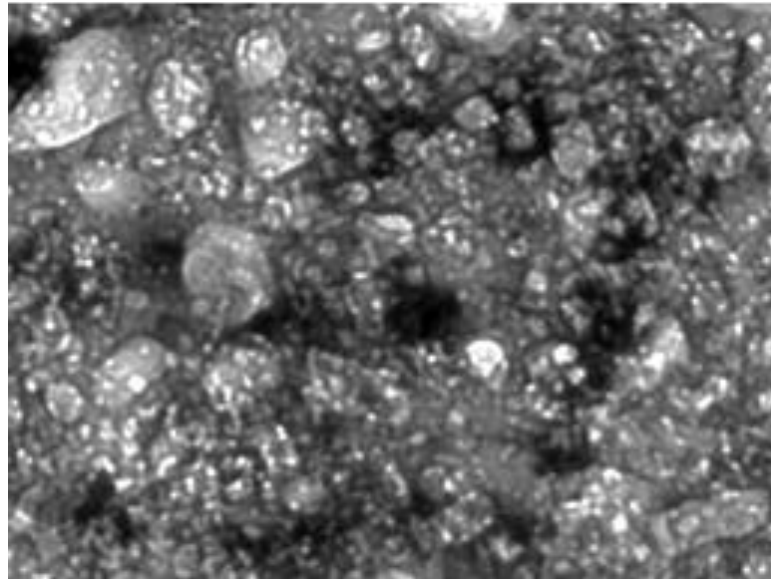
10 keV He then 3 MeV Ni

**Bubble to cavity  
transition and cavity  
evolution can be  
directly studied**

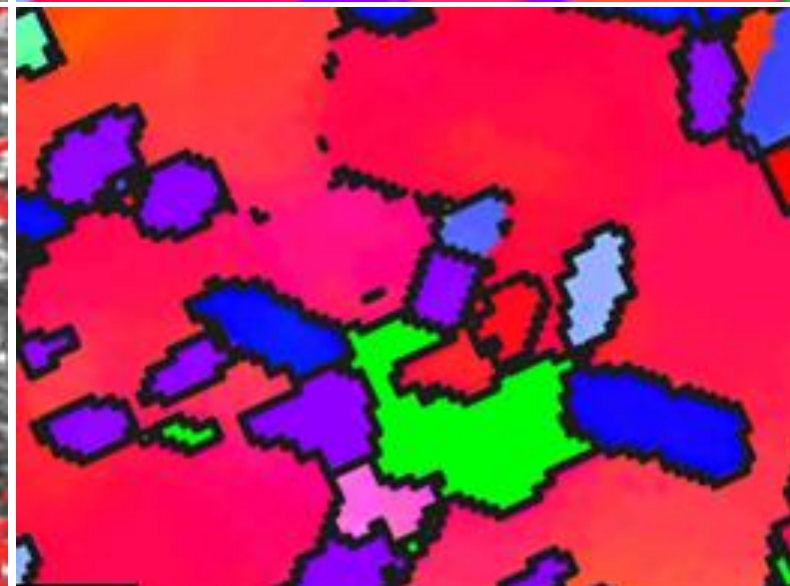
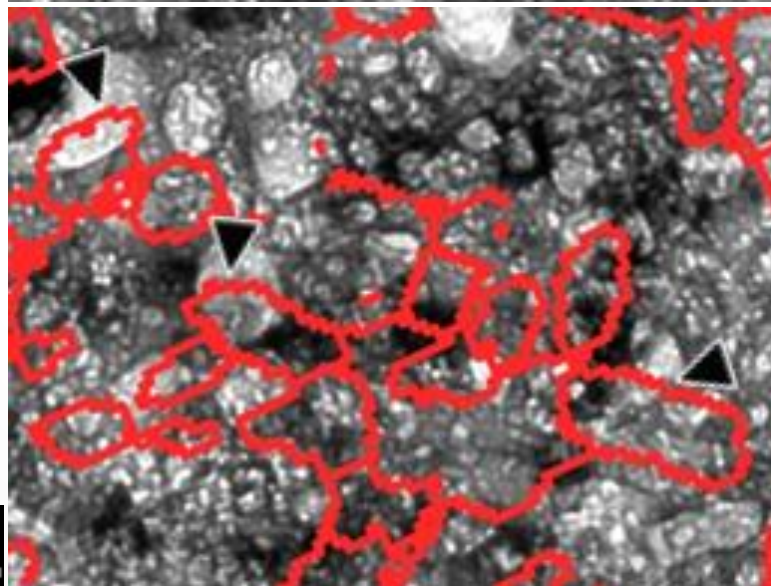


# Precession Electron Diffraction Reveals Hidden Grain Structure

Cavities in helium implanted,  
self-ion irradiated, nc nickel  
film annealed to 400 °C



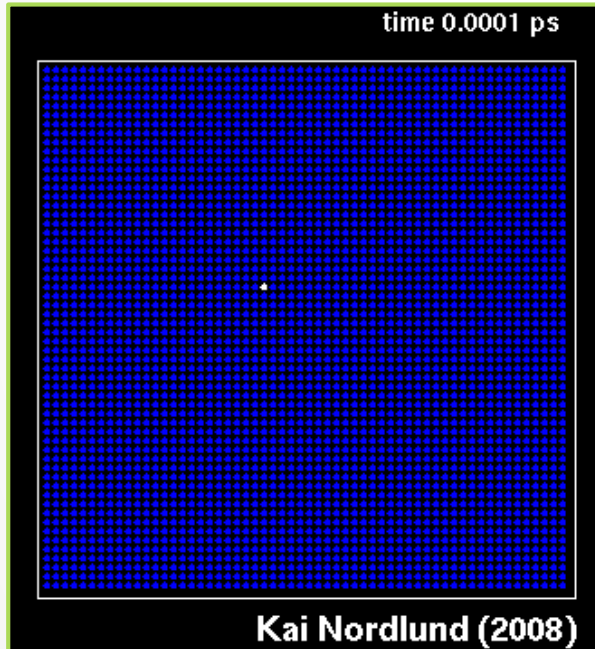
Cavities span multiple  
grains at identified grain  
boundaries





# Summary and the Future

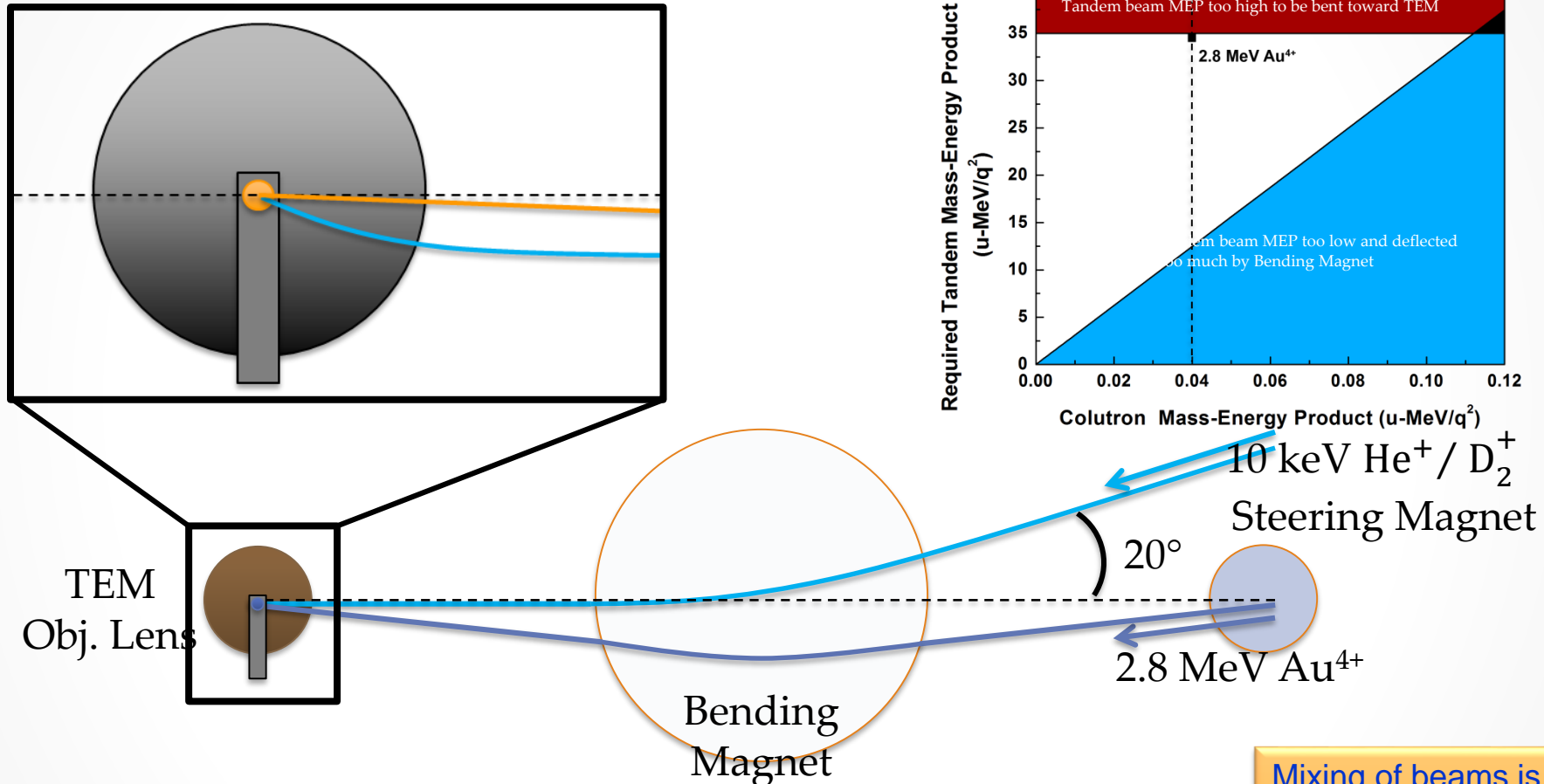
- Enhanced cavity nucleation with concurrent helium implantation and displacement damage
- Total fluence and irradiation order do affect cavity evolution, but temperature has the most dramatic effects
- Combination with orientation mapping begins to clarify the role of local microstructure



Acknowledgements: **IBL:** D.L. Buller, B.L. Doyle, C. Gong, M.T. Marshall, M. Steckbeck. **Sandia:** F.F. Abdeljawad, D.P. Adams, J.A. Scott, C. Sobczak. **External:** A. Minor, (UC Berkley), A. Darbal (AppFive), A. Leff (Drexel University). Work performed by DCB at Sandia was fully supported by the Division of Materials Science and Engineering, Office of Basic Energy Sciences, U.S. Department of Energy.

# Modeling Beam Mixing and Deflection

Collaborators: M. Steckbeck & B.L. Doyle

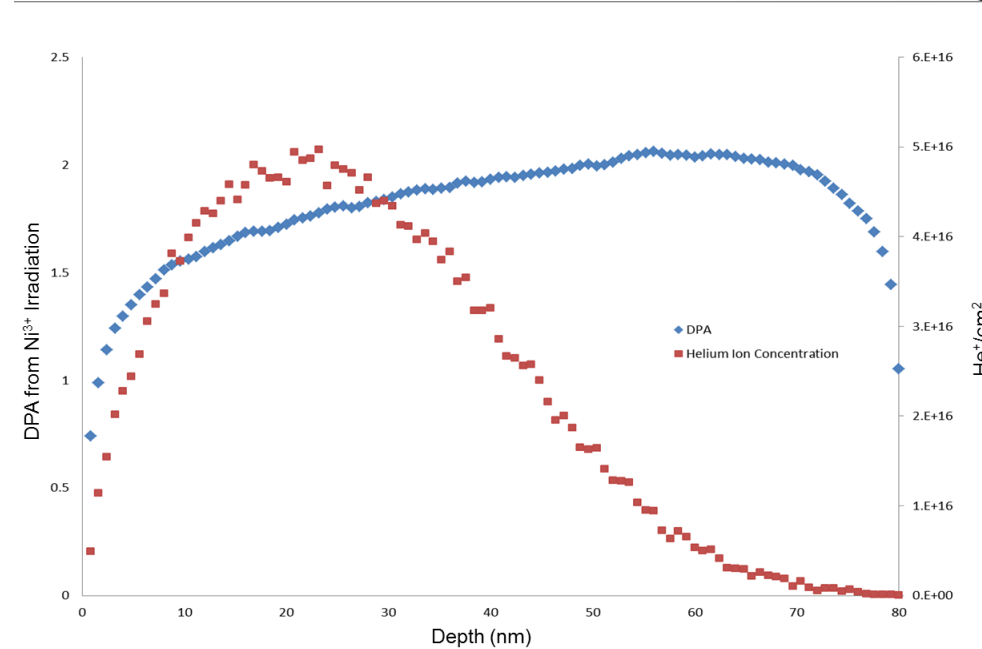
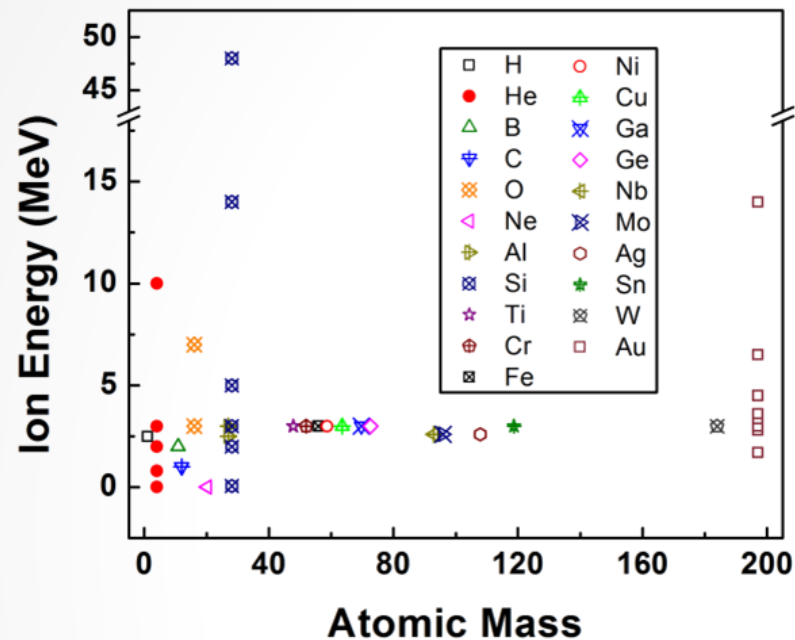


- Must compensate for deflection of Tandem beam by bending magnet
- Colutron beams deflected by the TEM objective lens
- Insignificant deflection of Tandem beams
- With  $10 \text{ keV He/D}_2$  we can use Tandem beams  $\gtrsim 13 \text{ MeV/q}^2$
- $\text{Au}$ ,  $\text{He}$ , and  $\text{D}_2$  ions all reach the sample concurrently

Mixing of beams is possible in limited conditions!

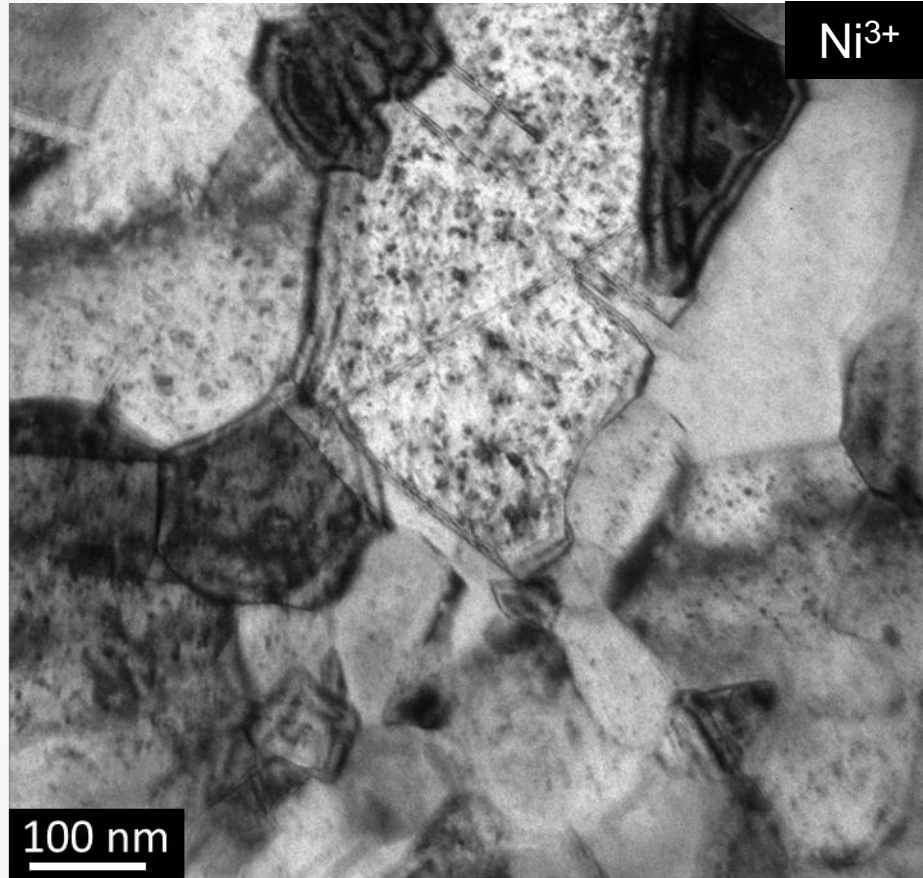


# Ion Beam Conditions

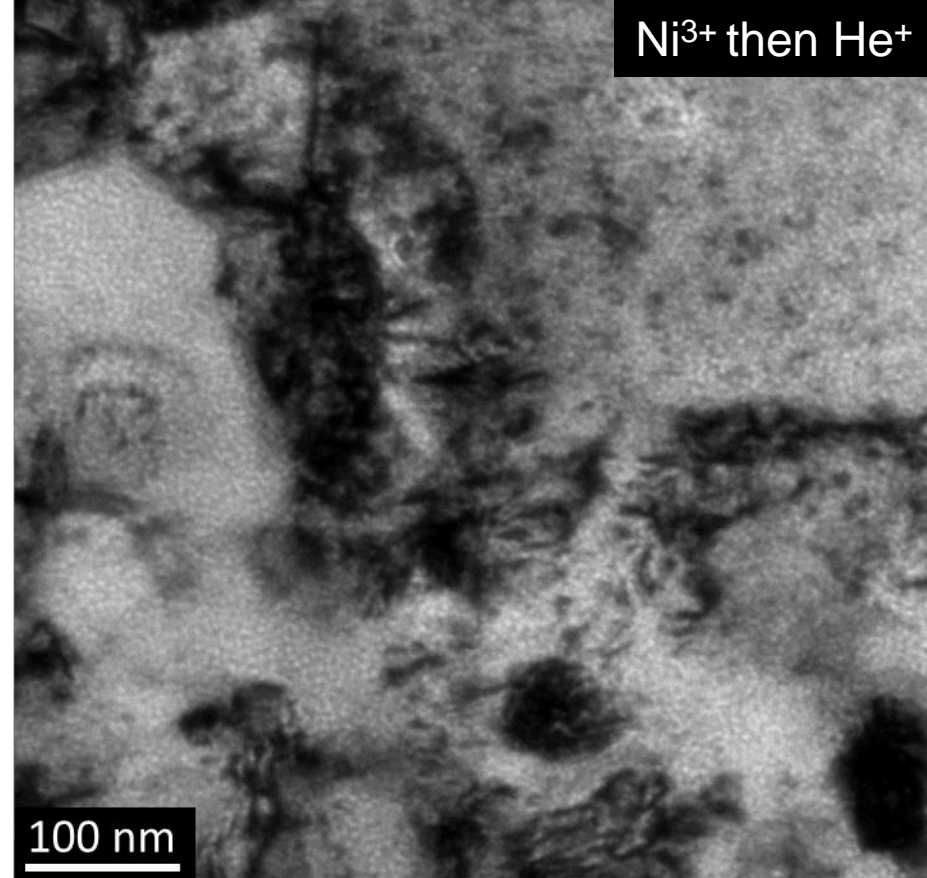


Order	Ni <sup>3+</sup> Rate	Ni <sup>3+</sup> damage	He Rate	He concentration
	ions/cm <sup>2</sup> s	DPA	ions/cm <sup>2</sup> s	ions/cm <sup>2</sup>
Ni <sup>3+</sup> , He <sup>+</sup>	1.5 E11	1.8	2.6 E 13	3 E 16
He <sup>+</sup> , Ni <sup>3+</sup>	1.5 E11	0.7	5.5 E13	1 E 17

# 3 MeV Ni<sup>3+</sup> Irradiation followed by 10 keV He<sup>+</sup> Implantation



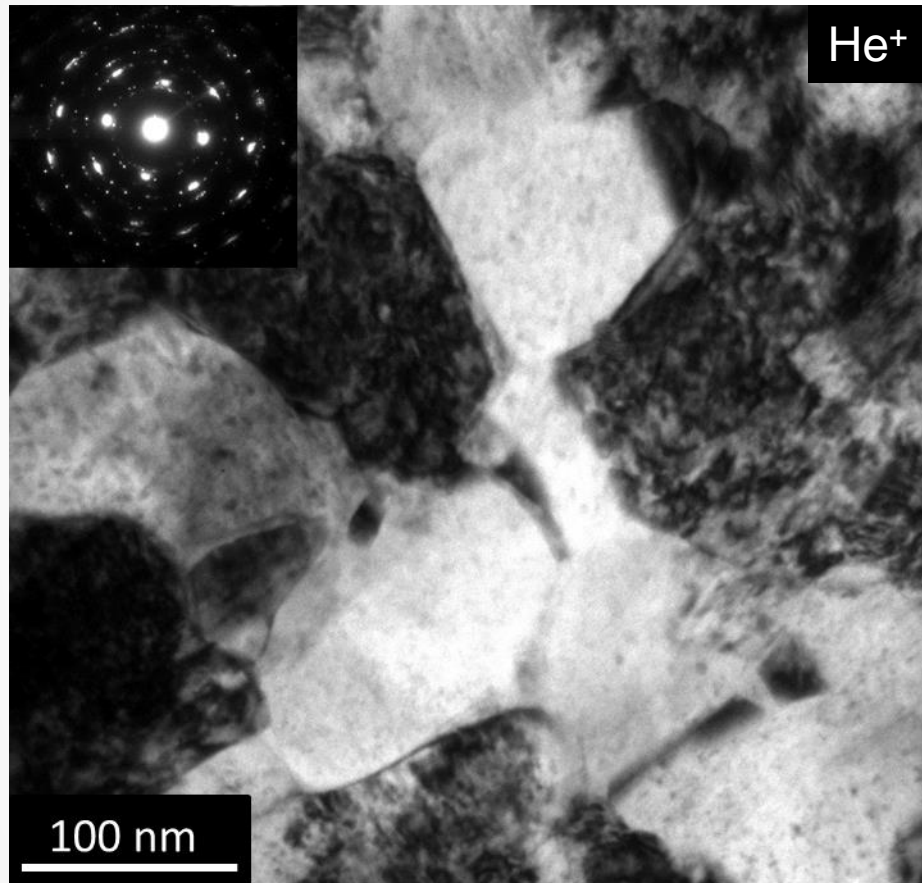
1.8 dpa Ni<sup>3+</sup> irradiation  
Dislocation loops and SFT are present



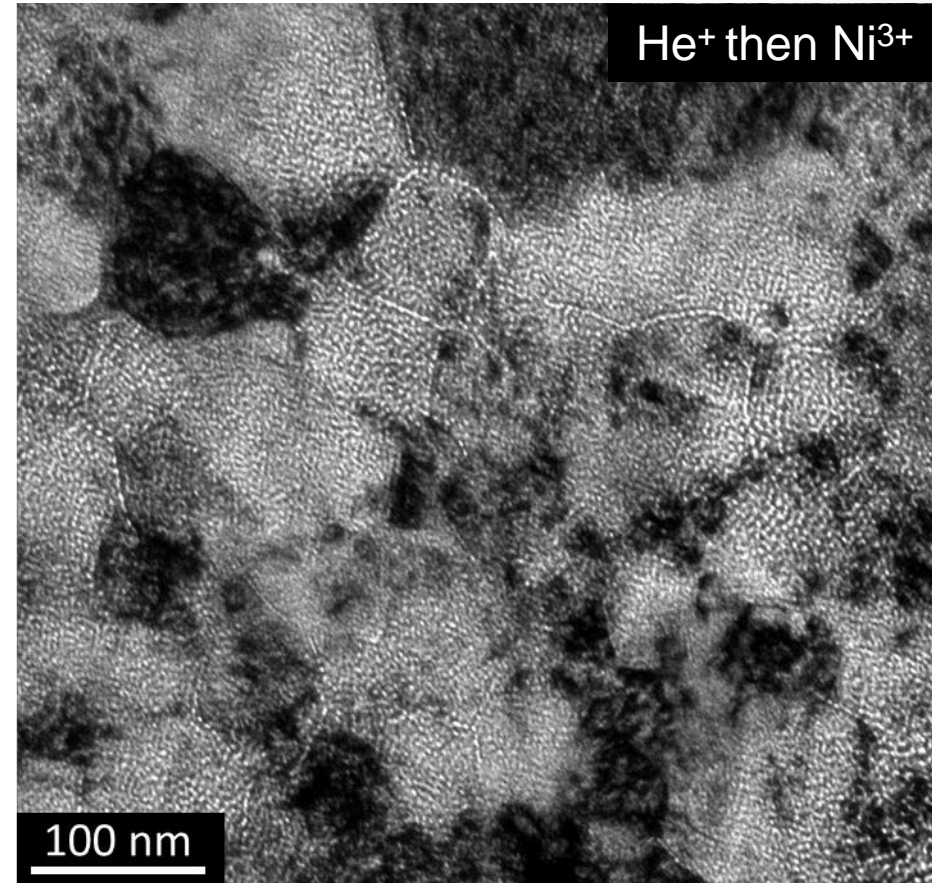
Additional 2x10<sup>16</sup> He<sup>+</sup>/cm<sup>2</sup>  
Evenly distributed  
nanometer size cavities



# 10 keV He<sup>+</sup> Implantation followed by 3 MeV Ni<sup>3+</sup> Irradiation



$10^{17}$  He<sup>+</sup>/cm<sup>2</sup>  
Visible damage

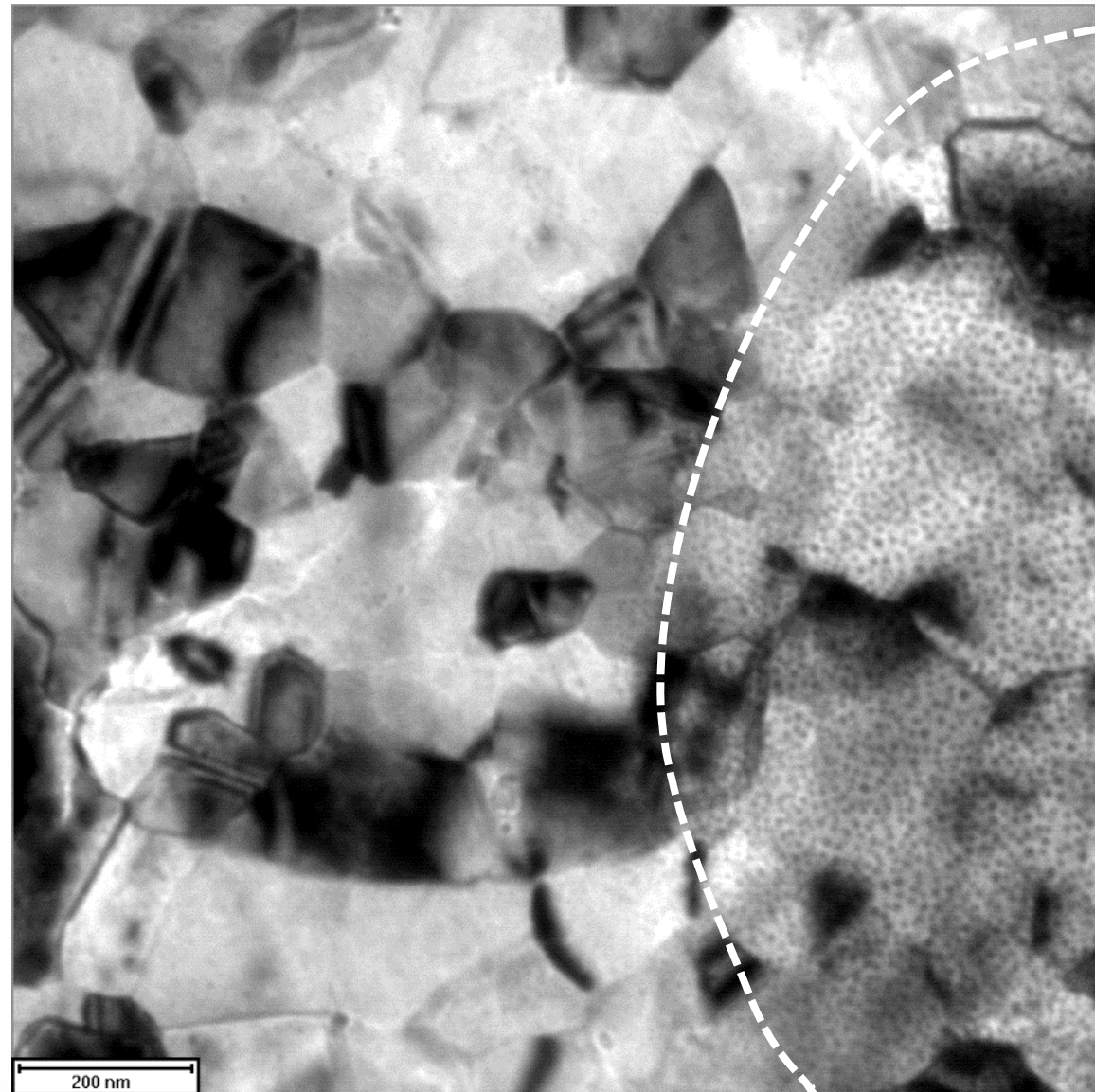


0.7 dpa Ni<sup>3+</sup> irradiation  
High concentration of cavities along grain  
boundaries

# Beam Effects

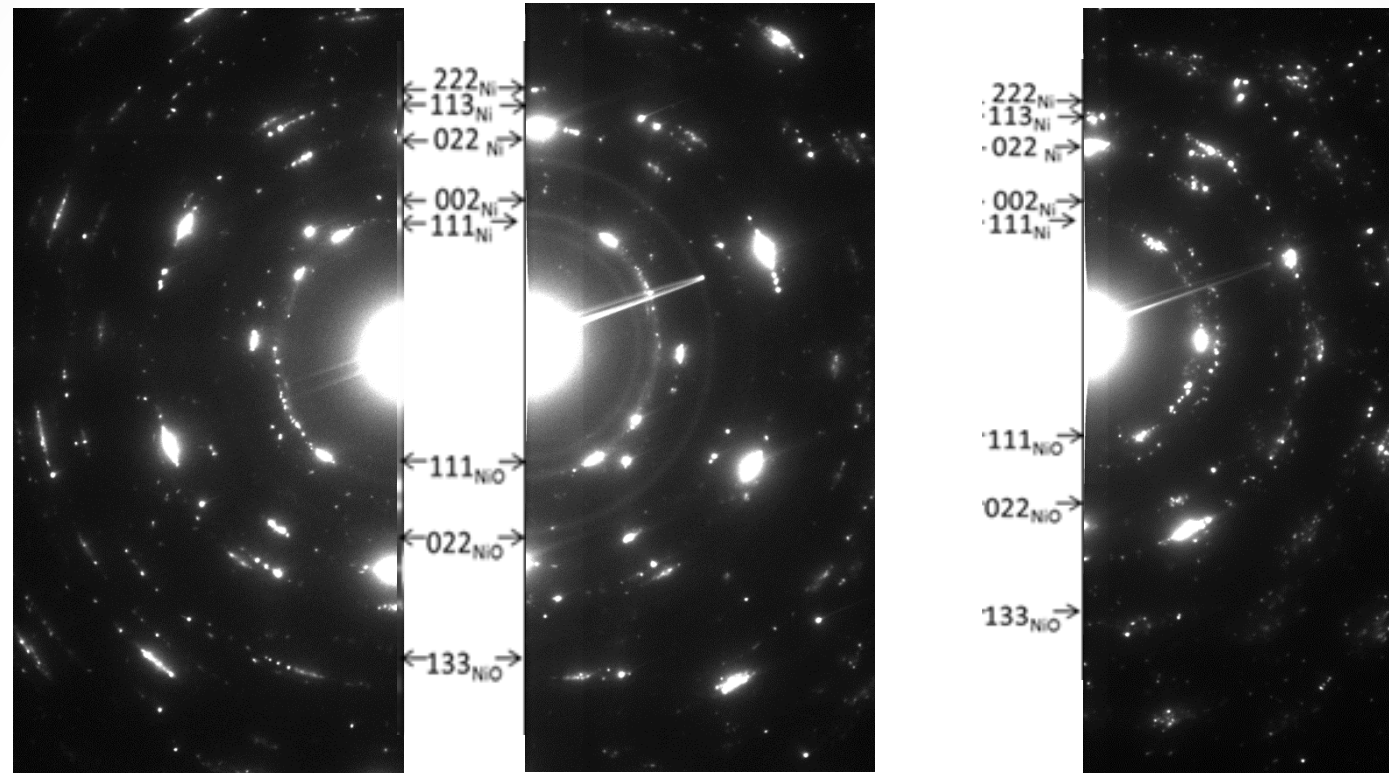
$$\Delta T \approx 2 \text{ K}$$

Max Energy  
Transferred = 14.5 eV  
Threshold E = 22 eV





# Growth



Include the diffusion model...